Characteristics STPS30M80C

1 Characteristics

Table 2. Absolute ratings (limiting values, per diode, at $T_{amb} = 25$ °C unless otherwise specified)

Symbol		Value	Unit				
V _{RRM}	Repetitive peak reverse vol	80	V				
I _{F(RMS)}	Forward rms current				30	Α	
I _{F(AV)}	Average forward current, $\delta = 0.5$	torward current, TO-220AB, I ² PAK, D ² PAK		Per diode Per device	15 30	А	
,	0 - 0.5	TO-220FPAB	T _c = 110 °C	Per diode	15		
I _{FSM}	Surge non repetitive forward current	$t_p = 10 \text{ ms sinusoidal}$ $T_c = 25 ^{\circ}\text{C}$			220	Α	
P _{ARM} ⁽¹⁾	Repetitive peak avalanche	power $T_j = 25$ °C, $t_p = 1 \mu s$			9500	W	
V _{ARM} ⁽²⁾	Maximum repetitive peak avalanche voltage	t_p < 1 μ s, T_j < 150 °C, I_{AR} < 28.2 A			100	V	
Tj	Maximum operating junction	175	°C				

For temperature or pulse time duration deratings, please refer to figure 3 and 4. More details regarding the avalanche energy measurements and diode validation in the avalanche are provided in the application notes AN1768 and AN2025.

Table 3. Thermal parameters

Symbol	Para	Value	Unit		
	TO-220AB		per diode	1.60	
	Junction to case	I ² PAK, D ² PAK total	0.88	°C/W	
R _{th(j-c)}	ounction to case	TO-220FPAB	per diode	5.20	C/VV
			total	4.15	
R _{th(c)}	TO-220AB Coupling I ² PAK, D ² PAK		0.15	°C/W	
		TO-220FPAB	TO-220FPAB		

When the two diodes 1 and 2 are used simultaneously:

$$\Delta T_j(diode\ 1) = P(diode\ 1)\ x\ R_{th(j-c)}(Per\ diode) + P(diode\ 2)\ x\ R_{th(c)}$$

^{2.} See Figure 13

^{3.} $\frac{dPtot}{dTj} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

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Table 4.	Static electrical	characteristics ((per diode)
IUDIC T.	Otatio Cicoti ioai	Ullul dottel lotion	pci diode,

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Deveroe leekoge eurrent	T _j = 25 °C	V 90 V	-	8	40	μΑ
'R`	Reverse leakage current	T _j = 125 °C	$V_R = 80 \text{ V}$	-	7	25	mA
		T _j = 25 °C	I _F = 7.5 A	-	0.570	0.620	
	$V_{F}^{(2)} \qquad \text{Forward voltage drop} \qquad \begin{array}{c} T_{j} = 125 \text{ °C} \\ \hline T_{j} = 25 \text{ °C} \\ \hline T_{j} = 125 \text{ °C} \\ \hline T_{j} = 125 \text{ °C} \\ \hline T_{i} = 25 \text{ °C} \\ \hline \end{array}$	T _j = 125 °C		-	0.490	0.530	
V (2)		T _j = 25 °C	I _F = 15 A	-	0.675	0.745	V
VF`		T _j = 125 °C		-	0.575	0.625	V
		T _j = 25 °C	1 20 4	-	0.815	0.910	
		I _F = 30 A	-	0.680	0.795		

- 1. Pulse test: t_p = 5 ms, δ < 2 %
- 2. Pulse test: t_p = 380 μ s, δ < 2 %

To evaluate the conduction losses use the following equation:

 $P = 0.455 \times I_{F(AV)} + 0.0113 \times I_{F}^{2}_{(RMS)}$

Figure 2. Average forward power dissipation Figure 3. Average forward current versus average forward current ambient temperature (per diode) $(\delta = 0.5, \text{ per diode})$

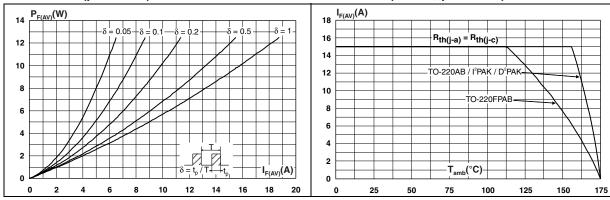
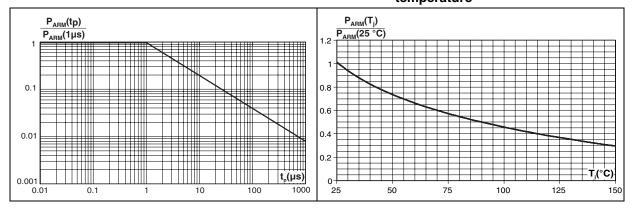


Figure 4. Normalized avalanche power derating versus pulse duration

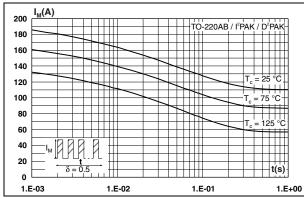
Figure 5. Normalized avalanche power derating versus junction temperature



Characteristics STPS30M80C

Figure 6. Non repetitive surge peak forward current versus overload duration (maximum values, per diode)

Figure 7. Non repetitive surge peak forward current versus overload duration (maximum values, per diode)



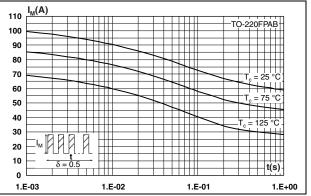
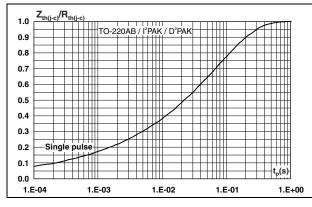


Figure 8. Relative thermal impedance junction to case versus pulse duration

Figure 9. Relative thermal impedance junction to case versus pulse duration (TO-220FPAB)



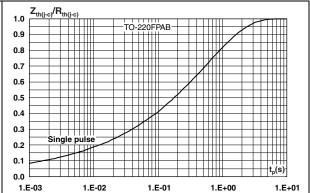
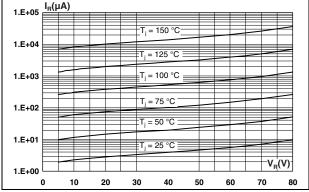
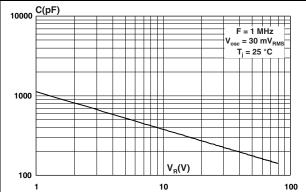


Figure 10. Reverse leakage current versus reverse voltage applied (typical values, per diode)

Figure 11. Junction capacitance versus reverse voltage applied (typical values, per diode)

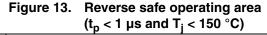


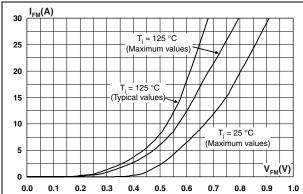


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Figure 12. Forward voltage drop versus forward current (per diode)





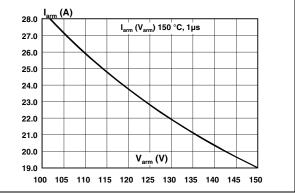
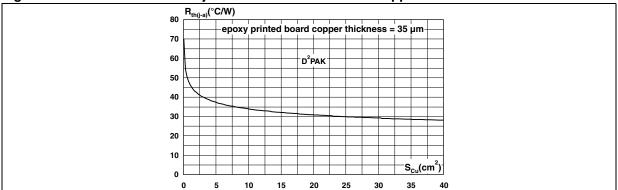


Figure 14. Thermal resistance junction to ambient versus copper surface under tab for D²PAK

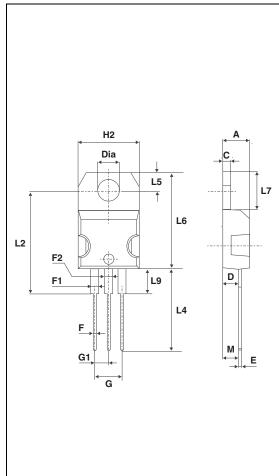


2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.4 to 0.6 N⋅m

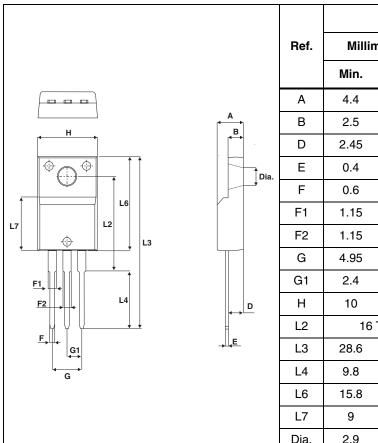
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Table 5. TO-220AB dimensions



	Dimensions					
Ref.	Millimeters		Inc	hes		
	Min.	Max.	Min.	Max.		
Α	4.40	4.60	0.173	0.181		
С	1.23	1.32	0.048	0.051		
D	2.40	2.72	0.094	0.107		
Е	0.49	0.70	0.019	0.027		
F	0.61	0.88	0.024	0.034		
F1	1.14	1.70	0.044	0.066		
F2	1.14	1.70	0.044	0.066		
G	4.95	5.15	0.194	0.202		
G1	2.40	2.70	0.094	0.106		
H2	10	10.40	0.393	0.409		
L2	16.4	Тур.	0.645 Typ.			
L4	13	14	0.511	0.551		
L5	2.65	2.95	0.104	0.116		
L6	15.25	15.75	0.600	0.620		
L7	6.20	6.60	0.244	0.259		
L9	3.50	3.93	0.137	0.154		
М	2.6 Typ.		0.102 Typ.			
Dia.	3.75	3.85	0.147	0.151		

Table 6. TO-220FPAB dimensions



	Dimensions					
Ref.	Millim	neters	Inches			
	Min.	Max.	Min.	Max.		
Α	4.4	4.9	0.173	0.192		
В	2.5	2.9	0.098	0.114		
D	2.45	2.75	0.096	0.108		
Е	0.4	0.7	0.016	0.028		
F	0.6	1	0.024	0.039		
F1	1.15	1.7	0.045	0.067		
F2	1.15	1.7	0.045	0.067		
G	4.95	5.2	0.195	0.205		
G1	2.4	2.7	0.094	0.106		
Н	10	10.7	0.394	0.421		
L2	16	Тур.	0.630	Тур.		
L3	28.6	30.6	1.126	1.205		
L4	9.8	10.7	0.386	0.421		
L6	15.8	16.4	0.622	0.646		
L7	9	9.9	0.354	0.390		
Dia.	2.9	3.5	0.114	0.138		

Package information STPS30M80C

Table 7. D²PAK dimensions

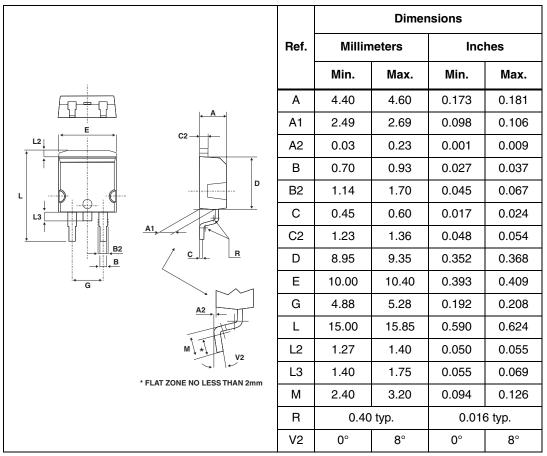
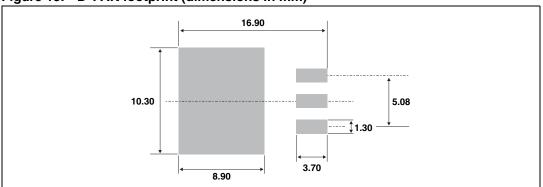
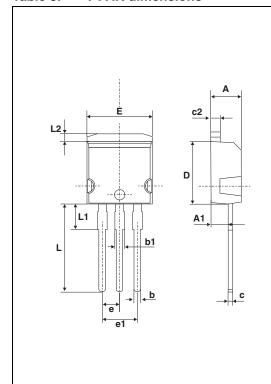


Figure 15. D²PAK footprint (dimensions in mm)



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Table 8. I²PAK dimensions



	Dimensions					
Ref.	Millim	neters	Inches			
	Min.	Max.	Min.	Max.		
Α	4.40	4.60	0.173	0.181		
A1	2.40	2.72	0.094	0.107		
b	0.61	0.88	0.024	0.035		
b1	1.14	1.70	0.044	0.067		
С	0.49	0.70	0.019	0.028		
c2	1.23	1.32	0.048	0.052		
D	8.95	9.35	0.352	0.368		
е	2.40	2.70	0.094	0.106		
e1	4.95	5.15	0.195	0.203		
Е	10	10.40	0.394	0.409		
L	13	14	0.512	0.551		
L1	3.50	3.93	0.138	0.155		
L2	1.27	1.40	0.050	0.055		

3 Ordering information

Table 9. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS30M80CT	STPS30M80CT	TO-220AB	1.9 g	50	Tube
STPS30M80CFP	STPS30M80CFP	TO-220FPAB	2.0 g	50	Tube
STPS30M80CR	STPS30M80CR	I ² PAK	1.49 g	50	Tube
STPS30M80CG-TR	STPS30M80CG	D ² PAK	1.48 g	1000	Tape and reel

4 Revision history

Table 10. Revision history

Date	Revision	Changes
11-Apr-2011 1		First issue.

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